

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re Application of: Janice Nickel

Docket No.: 10991744-4

Serial No. : Not Assigned

Group Art Unit: Not Assigned

Filed: Not Assigned

Examiner: Not Assigned

**Title: MRAM Device Including Spin Dependent Tunneling Junction Memory Cells
{As Amended herein}**

A Divisional of: Janice Nickel

Docket No.: 10991744-1

Serial No. : 09/514,934

Group Art Unit: 2823

Filed: 02/08/2000

Examiner: Neal Berezny

**Title: Method of Fabricating an MRAM Device Including Spin Dependent
Tunneling Junction Memory Cells**

PRELIMINARY AMENDMENT AND RESPONSE UNDER 37 C.F.R. §1.115

Assistant Commissioner for Patents
Washington, DC 20231

Sir:

Please consider this Divisional Application in light of the following preliminary amendments and remarks.

Please amend the above application as follows: